

AMENDMENTS TO THE CLAIMS

1. (Currently Amended) A liquid crystal display (LCD) device, comprising:
a thin film transistor (TFT) formed on a substrate, the TFT having a gate,
a source and a drain;

a color filter layer ~~formed on the TFT, to be~~ and in direct contact with ~~at least the source or~~ and the drain, wherein said contact is only at a portion where said color filter layer is overlapping only edge portions of the source and drain;
and

a pixel electrode formed above the color filter layer to be in electrical contact with the drain.

2. (Currently Amended) The device of claim 1, wherein the color filter layer
~~and at least the source or the~~ drain are in direct contact such that there are no intermediaries therebetween.

3. (Currently Amended) A method of manufacturing a liquid crystal display (LCD) device, comprising:

forming a thin film transistor (TFT) on a substrate, the TFT having a gate,
a source and a drain;

forming a color filter layer on the TFT, ~~to be~~ in direct electrical contact with ~~at least the source or~~ and the drain, wherein said electrical contact is only at a portion where said color filter layer is overlapping only edge portions of the source and drain; and

forming a pixel electrode above the color filter layer to be in electrical contact with the drain.

4. (Currently Amended) The method according to claim 3, wherein the LCD is manufactured without forming a passivation layer between the TFT and the color filter layer.